



ELECTRONICS, INC.
44 FARRAND STREET
BLOOMFIELD, NJ 07003
(973) 748-5089
<http://www.nteinc.com>

GI750 thru GI758 6 Amp Plastic Silicon Rectifier

Features:

- Low Forward Voltage Drop
- Low Leakage Current, I_R less than $0.1\mu A$
- High Forward Current Capability
- High Forward Surge Capability

Absolute Maximum Ratings: ($T_A = +25^\circ C$ unless otherwise specified)

Maximum Repetitive Peak Reverse and Blocking Voltage, V_{RRM} , V_{DC}

GI750	50V
GI751	100V
GI752	200V
GI754	400V
GI756	600V
GI758	800V

Maximum RMS Voltage, V_{RMS}

GI750	35V
GI751	70V
GI752	140V
GI754	280V
GI756	420V
GI758	560V

Maximum Non-Repetitive Peak Reverse Voltage, V_{RSM}

GI750	60V
GI751	120V
GI752	240V
GI754	480V
GI756	720V
GI758	1200V

Maximum Average Forward Rectified Current ($T_A = +60^\circ C$), $I_{F(AV)}$

PC Board Mounting	6A
.125" (3.18mm) Lead Length	22A

Peak Forward Surge Current (8.3ms single half sine-wave superimposed on rated load) . . . 400A

Operating Junction Temperature Range, T_J . . . -65° to $+175^\circ C$

Storage Temperature Range, T_{stg} . . . -65° to $+175^\circ C$

Typical Thermal Resistance (Note 1)

Junction-to-Ambient, R_{thJA}	$20^\circ C/W$
Junction-to-Lead, R_{thJL}	$4.0^\circ C/W$

Note 1. Thermal resistance from junction to ambient and from junction to lead at 0.375" (9.5mm) lead length, PB board mounted with 1.1" x 1.1" (30mm x 30mm) copper pads.

Electrical Characteristics: ($T_A = +25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Instantaneous Forward Voltage GI750 thru GI756	V_F	$I_F = 6\text{A}$	–	–	0.90	V
		$I_F = 100\text{A}$	–	–	1.25	V
		$I_F = 6\text{A}$	–	–	0.95	V
		$I_F = 100\text{A}$	–	–	1.30	V
DC Reverse Current	I_R	At Rated V_{DC}	$T_A = +25^{\circ}\text{C}$	–	5.0	μA
			$T_A = +100^{\circ}\text{C}$	–	1.0	mA
Reverse Recovery Time	t_{rr}	$I_F = 0.5\text{A}, I_R = 1\text{A}, I_{rr} = 0.25\text{A}$	–	2.5	–	μs
Junction Capacitance	C_J	4V, 1MHz	–	150	–	pF

